L Number	Hits	Search Text	DB	Time stamp
1	2	(("5372967") or ("6236538")).PN.	USPAT;	2004/05/04 09:05
		((US-PGPUB	200 11 03/01 03:03
2	1406967	cylind\$8 rod circle "semi-circle" semi near3 cycle	USPAT;	2004/05/04 09:07
_		Symbol 104 on the Serial break Serial means by the	US-PGPUB	2004/03/04 03:07
3	48673	inductor	USPAT;	2004/05/04 09:07
		maavevi	US-PGPUB	2004/03/04 03:07
4	11849	(cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor	USPAT;	2004/05/04 09:09
·	11015	(cylindae rod enere senii enere senii nears cycle) and madelor	US-PGPUB	2004/03/04 03.09
5	399609	semiconductor	USPAT;	2004/05/04 09:10
	277007	bernoond door	US-PGPUB	2004/03/04 09.10
6	404672	semiconductor semiconductive	USPAT;	2004/05/04 09:10
ŭ	,0.0.2	on a contract of someon audit of	US-PGPUB	2004/03/04 09.10
7	3107	((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:10
,	5107	(semiconductor semiconductive)	US-PGPUB	2004/03/04 09.10
8	627772	substrate	USPAT;	2004/05/04 09:10
	02,772	Substitute	US-PGPUB	2004/03/04 09.10
9	1688	(((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:10
	1000	((semiconductor semiconductive)) and substrate	US-PGPUB	2004/03/04 09.10
10	573264	groove trench	USPAT;	2004/05/04 09:11
	0,020.		US-PGPUB	2004/03/04 09.11
11	534	((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:11
		(semiconductor semiconductive)) and substrate) and (groove trench)	US-PGPUB	2004/03/04 09.11
12	355	(((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:33
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	2004/05/04 07:55
		@ad<20010831	COTOLOB	
13	855982	insulating insulator oxide	USPAT;	2004/05/04 11:24
		0	US-PGPUB	2004/05/04 11:24
14	30770	(groove trench) with (insulating insulator oxide)	USPAT;	2004/05/04 09:21
		(B and	US-PGPUB	2004/03/04 09.21
15	75	((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:32
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	2004/05/04 07.52
		@ad<20010831) and ((groove trench) with (insulating insulator oxide))	CD I GI CD	
16	5	("3305814" "5008176" "5112438" "5748523" "6303971").PN.	USPAT	2004/05/04 09:26
17	4	("3290758" "3614554" "5372967" "5514832").PN.	USPAT	2004/05/04 09:30
18	280	((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:33
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	200 1/03/04 07:55
		@ad<20010831) not (((((((cylind\$8 rod circle "semi-circle" semi near3 cycle	00.00	
) and inductor) and (semiconductor semiconductive)) and substrate) and		
		(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
		insulator oxide)))		
19	131	(((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	USPAT;	2004/05/04 09:38
		(semiconductor semiconductive)) and substrate) and (groove trench)) and	US-PGPUB	
		@ad<20010831) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle		
) and inductor) and (semiconductor semiconductive)) and substrate) and		
		(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
		insulator oxide)))) and @ad<19971119		
20	666	inductor and ((groove trench) with (insulating insulator oxide))	USPAT;	2004/05/04 09:38
			US-PGPUB	
21	591	(inductor and ((groove trench) with (insulating insulator oxide))) not	USPAT;	2004/05/04 09:38
	ŀ	((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and	US-PGPUB	
		(semiconductor semiconductive)) and substrate) and (groove trench)) and		
		@ad<20010831) not (((((((cylind\$8 rod circle "semi-circle" semi near3 cycle		
) and inductor) and (semiconductor semiconductive)) and substrate) and		
	-	(groove trench)) and @ad<20010831) and ((groove trench) with (insulating		
	-	insulator oxide)))) not (((((((cylind\$8 rod circle "semi-circle" semi near3		
		cycle) and inductor) and (semiconductor semiconductive)) and substrate)		
		and (groove trench)) and @ad<20010831) and ((groove trench) with	İ	
		(insulating insulator oxide)))		

22	149	((inductor and ((groove trench) with (insulating insulator oxide))) not	USPAT;	2004/05/04 10:13
		((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) not ((((((cylind\$8 rod circle "semi-circle" semi near3 cycle) and inductor) and (semiconductor semiconductive)) and substrate) and	US-PGPUB	
		(groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide)))) not ((((((cylind\$8 rod circle "semi-circle" semi near3		
		cycle) and inductor) and (semiconductor semiconductive)) and substrate) and (groove trench)) and @ad<20010831) and ((groove trench) with (insulating insulator oxide)))) and @ad<19971119		
23	33818	magnetic near4 core	USPAT; US-PGPUB	2004/05/04 10:09
24	95347	inductor inductive	USPAT; US-PGPUB	2004/05/04 11:07
25	7747	(magnetic near4 core) and (inductor inductive)	USPAT; US-PGPUB	2004/05/04 10:10
26	1741	(semiconductor semiconductive) and ((magnetic near4 core) and (inductor inductive))	USPAT; US-PGPUB	2004/05/04 10:10
27	25318	(semiconductor semiconductive) and (inductor inductive)	USPAT;	2004/05/04 10:10
28	23577	((semiconductor semiconductive) and (inductor inductive)) not ((semiconductor semiconductive) and ((magnetic near4 core) and (inductor	US-PGPUB USPAT;	2004/05/04 10:11
29	375966	inductive))) core	US-PGPUB	
			USPAT; US-PGPUB	2004/05/04 11:23
30	23493	(insulating insulator oxide) with core	USPAT; US-PGPUB	2004/05/04 10:12
31	2156	(inductor inductive) and ((insulating insulator oxide) with core)	USPAT; US-PGPUB	2004/05/04 10:12
32	494	(semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))	USPAT; US-PGPUB	2004/05/04 10:28
33	177	((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 10:29
34	3650	(semiconductor semiconductive) and ((insulating insulator oxide) with core)	USPAT; US-PGPUB	2004/05/04 10:29
35	396677	coil	USPAT; US-PGPUB	2004/05/04 10:29
36	920	((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil	USPAT; US-PGPUB	2004/05/04 10:29
37	393	(((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119	USPAT; US-PGPUB	2004/05/04 11:19
38	265	(((((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119) not (((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and	USPAT; US-PGPUB	2004/05/04 10:30
39	103	@ad<19971119)		
	103	substrate and (((((semiconductor semiconductive) and ((insulating insulator oxide) with core)) and coil) and @ad<19971119) not (((semiconductor semiconductive) and ((inductor inductive) and ((insulating insulator oxide) with core))) and @ad<19971119))	USPAT; US-PGPUB	2004/05/04 11:06
40	62585	polysilicon	USPAT;	2004/05/04 11:38
41	454129	inductor inductive coil	US-PGPUB USPAT;	2004/05/04 11:38
42	4231	polysilicon and (inductor inductive coil)	US-PGPUB USPAT;	2004/05/04 11:07
43	1276	(polysilicon and (inductor inductive coil)) and @ad<19971119	US-PGPUB USPAT;	2004/05/04 11:08
44	17	((insulating insulator oxide) with core) and ((polysilicon and (inductor inductive coil)) and @ad<19971119)	US-PGPUB USPAT;	2004/05/04 11:17
45	796328	oxid\$6	US-PGPUB USPAT;	2004/05/04 11:36
46	71504	(inductor inductive coil) and oxid\$6	US-PGPUB USPAT;	2004/05/04 11:18
47	40416	((inductor inductive coil) and oxid\$6) and @ad<19971119	US-PGPUB USPAT; US-PGPUB	2004/05/04 11:25

48	1022	polysilicon and (((inductor inductive coil) and oxid\$6) and @ad<19971119)	USPAT;	2004/05/04 11:19
.0	1022	portanicon and (((industric con) and oxidato) and ((industric con))	US-PGPUB	2007/03/07 11.19
49	16	((insulating insulator oxide) with core) and (polysilicon and (((inductor	USPAT;	2004/05/04 11:20
		inductive coil) and oxid\$6) and @ad<19971119))	US-PGPUB	
50	234540	inductor inductive coil	ЕРО; ЈРО;	2004/05/04 11:29
	211226		IBM_TDB	
51	211236	core	EPO; JPO;	2004/05/04 11:28
53	470405		IBM_TDB	2004/05/04 11 20
52	479495	insulating insulator oxide	EPO; JPO;	2004/05/04 11:28
53	5126	(inductor inductive coil) and core and (insulating insulator oxide)	IBM_TDB EPO; JPO;	2004/05/04 11:26
33	3120	(madelor inductive con) and core and (misurating misurator oxide)	IBM TDB	2004/03/04 11.20
54	2634	(inductor inductive coil) with core with (insulating insulator oxide)	EPO; JPO;	2004/05/04 11:24
		(managing managing only)	IBM TDB	200 11 037 01 11:24
55	0	((inductor inductive coil) with core with (insulating insulator oxide)) and	USPAT;	2004/05/04 11:50
		@ad<19971119	US-PGPUB	
56	13068	polysilicon	ЈРО;	2004/05/04 11:27
			IBM_TDB	
57	1	((inductor inductive coil) with core with (insulating insulator oxide)) and	JPO;	2004/05/04 11:27
		polysilicon	IBM_TDB	
58	1	((inductor inductive coil) and core and (insulating insulator oxide)) and	EPO; JPO;	2004/05/04 11:27
		polysilicon	IBM_TDB	
59	14448	polysilicon	EPO; JPO;	2004/05/04 11:30
60	١.,	(Godernton industrial and Desire to the Constant of the Consta	IBM_TDB	0004/05/04/14 05
60	1	((inductor inductive coil) with core with (insulating insulator oxide)) and polysilicon	JPO;	2004/05/04 11:27
61	290275	core	IBM_TDB DERWENT	2004/05/04 11:28
62	714947	insulating insulator oxide	DERWENT	2004/05/04 11:28
63	300876	inductor inductive coil	DERWENT	2004/05/04 11:28
64	2489	core same (insulating insulator oxide) same (inductor inductive coil)	DERWENT	2004/05/04 11:29
65	1547	core with (insulating insulator oxide) with (inductor inductive coil)	DERWENT	2004/05/04 11:29
66	16371	polysilicon	DERWENT	2004/05/04 11:30
67	2	(core with (insulating insulator oxide) with (inductor inductive coil)) and	DERWENT	2004/05/04 11:32
		polysilicon		
68	1	("6015742").PN.	USPAT;	2004/05/04 11:32
			US-PGPUB	
69	8	("3988764" "5372967" "5514832" "5767563" "5770509" "5825092"	USPAT	2004/05/04 11:32
		"5900764" "5917244").PN.		
70	238208	oxidi\$5	USPAT;	2004/05/04 11:36
7,		1 11 11 1166	US-PGPUB	
71	0	polysilicon with oxidi\$5	USPAT;	2004/05/04 11:36
72	4001	materitiaan erist arristos	US-PGPUB	2004/05/04 11 20
12	4081	polysilicon with oxidi\$5	USPAT;	2004/05/04 11:38
73	149	(inductor inductive coil) and (polysilicon with oxidi\$5)	US-PGPUB USPAT;	2004/05/04 11:20
13	149	(madetor madetive con) and (porysincon with oxidias)	USPAT; US-PGPUB	2004/05/04 11:39
74	56	((inductor inductive coil) and (polysilicon with oxidi\$5)) and	USPAT;	2004/05/04 11:51
' '	50	(inductor inductive con) and (porysmeon with oxidis5)) and (ad<19971119	US-PGPUB	2004/03/04 11:31
	L	Cyme 1//111/	00-1 01 0D	